SQR40020ER

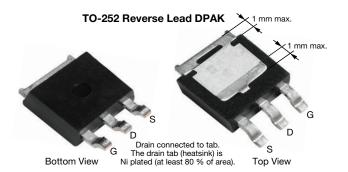
www.vishay.com

Vishay Siliconix

RoHS

COMPLIANT

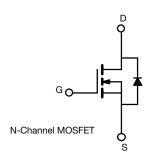
Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.00233			
I _D (A)	100			
Configuration	Single			
Package	TO-252 reverse lead DPAK			

FEATURES

- TrenchFET[®] power MOSFET
- · Package with low thermal resistance
- Ni plated drain tab area (heatsink) for top side cooling
- 100 % R_g and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS (To	_C = 25 °C, unles	s otherwise notec)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	40	V	
Gate-source voltage		V _{GS}	± 20	v	
Continuous drain current	$T_{C} = 25 \ ^{\circ}C \ ^{a}$	I-	100		
Continuous drain current	T _C = 125 °C	۱ _D	87.5		
Continuous source current (diode conduction)		I _S	97	А	
Pulsed drain current ^b		I _{DM}	280		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	46		
Single pulse avalanche energy		E _{AS}	105.8	mJ	
Maximum power dissipation ^b	T _C = 25 °C	PD	107	W	
	T _C = 125 °C	۳D	35	VV	
Operating junction and storage temperature range)	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^c	R _{thJA}	50	°C/W	
Junction-to-case (drain)		R _{thJC}	1.4	0/10	

Notes

a. Package limited

b. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %

c. When mounted on 1" square PCB (FR4 material)

SQR40020ER

SPECIFICATIONS ($T_C = 25 \ ^{\circ}C$,	unless other	wise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$		40	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	2.5	3.0	3.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 175 °C	-	-	500	μA
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	50	-	-	Α
		V _{GS} = 10 V	I _D = 20 A	-	0.00190	0.00233	
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A, T _J = 125 °C	-	-	0.00390	Ω
	. ,	V _{GS} = 10 V	I _D = 20 A, T _J = 175 °C	-	-	0.00470	
Forward transconductance ^b	g _{fs}	V _{DS}	= 15 V, I _D = 20 A	-	84	-	S
Dynamic ^b					•	•	
Input capacitance	C _{iss}			-	5405	8000	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	1942	2700	pF
Reverse transfer capacitance	C _{rss}			-	175	250	
Total gate charge ^c	Qg			-	84	130	
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	= 10 V V _{DS} = 20 V, I _D = 50 A		29.5	-	nC
Gate-drain charge ^c	Q _{gd}			-	19.5	-	
Gate resistance	Rg	f = 1 MHz		1	2	3	Ω
Turn-on delay time ^c	t _{d(on)}			-	17	30	
Rise time ^c	t _r	- V _{DD} =	= 20 V, R _I = 0.4 Ω	-	17	30	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 50 \text{ A}, V_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		-	34	60	ns
Fall time ^c	t _f			-	18	35	
Source-Drain Diode Ratings and Chara	cteristics b				<u> </u>	•	
Pulsed current ^a	I _{SM}			-	-	280	А
Forward voltage	V _{SD}	I _F = 25 A, V _{GS} = 0 V		-	0.8	1.5	V
Body diode reverse recovery time	t _{rr}			-	41	85	ns
Body diode reverse recovery charge	Q _{rr}	- I _F = 50 A, di/dt = 100 A/μs		-	28	60	nC
Reverse recovery fall time	t _a			-	24	-	
Reverse recovery rise time	t _b	1		-	17	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.36	-	А

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

www.vishay.com

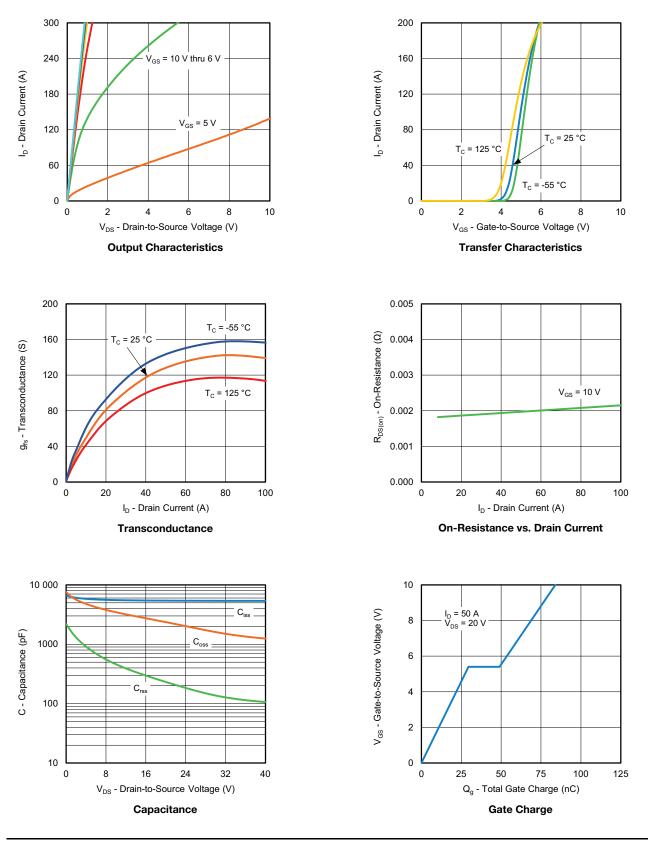
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



S19-0202-Rev. A, 04-Mar-2019

3 stions contact: automostechsupp Document Number: 76927

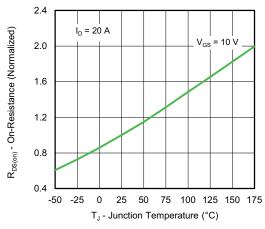
For technical questions, contact: <u>automostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



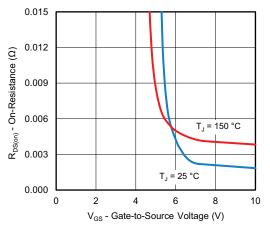
SQR40020ER

Vishay Siliconix

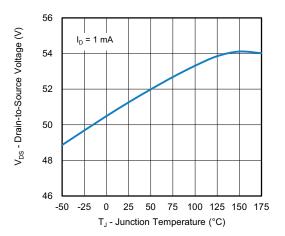
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



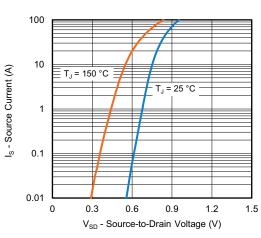
On-Resistance vs. Junction Temperature



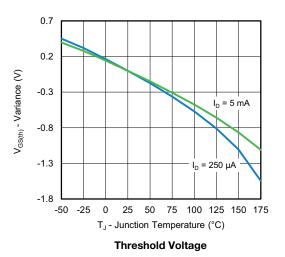
On-Resistance vs. Gate-to-Source Voltage

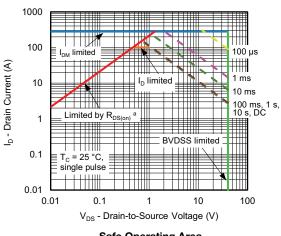


Drain Source Breakdown vs. Junction Temperature

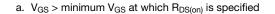


Source Drain Diode Forward Voltage





Safe Operating Area



S19-0202-Rev. A, 04-Mar-2019

4 For technical questions, contact: <u>automostechsupport@visl</u>

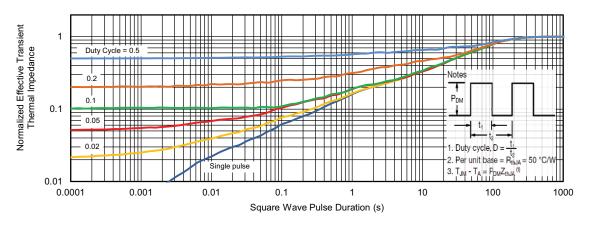
Note

Document Number: 76927

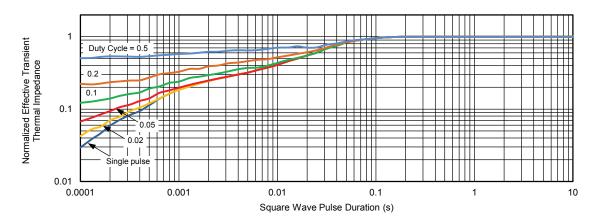
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

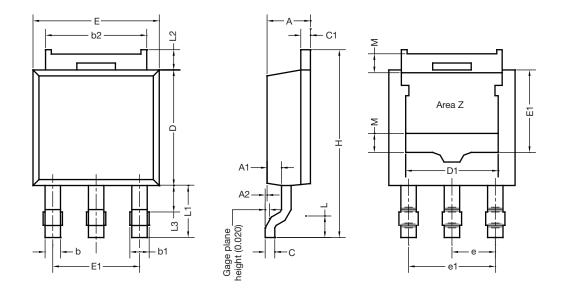
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?76927.

S19-0202-Rev. A, 04-Mar-2019	5	Document Number: 76927
	For technical questions, contact: <u>automostechsupport@vishay.co</u>	<u>m</u>
	T TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED IECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishav.co</u> r	



TO-252 Reverse Lead Case Outline



Notes

Dimension L3 for reference only

• Area Z: unplated area more than 80 % heatsink area and for partial plating part only

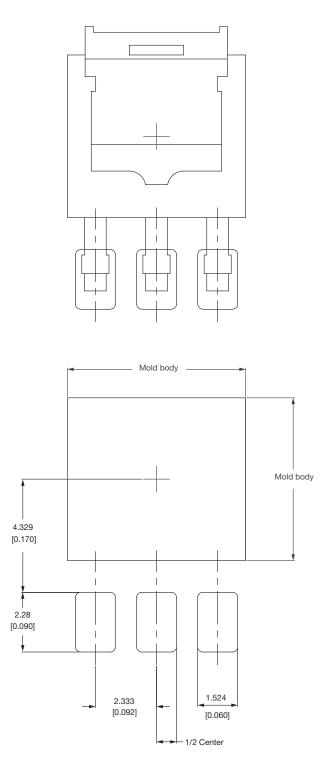
DIM.	MIL	LIMETERS	INCHES		
	MIN.	MAX.	MIN.	MAX.	
А	2.23	2.33	0.088	0.092	
A1	0.64	0.89	0.025	0.035	
A2	0.03	0.18	0.001	0.007	
b	0.71	0.88	0.028	0.035	
b1	0.76	1.14	0.030	0.045	
b2	5.23	5.44	0.206	0.214	
С	0.46	0.58	0.018	0.023	
C1	0.46	0.58	0.018	0.023	
D	5.97	6.22	0.235	0.245	
D1	4.49	5.00	0.177	0.197	
E	6.48	6.73	0.255	0.265	
E1	4.32	-	0.170	-	
е	2	2.28 BSC	0.090 BSC		
e1	4	I.57 BSC	0.180 BSC		
Н	9.65	10.41	0.380	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 BSC		
L2	0.89	1.27	0.035	0.050	
L3	1.15	1.52	0.040	0.060	
М	-	1.00 (reference only)	-	0.039 (reference only	



PAD Pattern

Vishay Siliconix

Recommended Land Pattern DPAK (TO-252) 3LR



Note

• Dimensions in mm (inches)

ECN: T22-0575-Rev. A, 12-Dec-2022 DWG: 3015

Revision: 12-Dec-2022

1

Document Number: 62165

For technical questions, contact: <u>pmostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.